



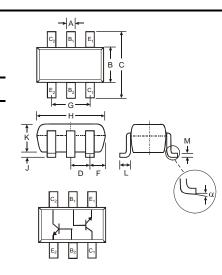
DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction** .
- Ideal for Low Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)

Mechanical Data

- Case: SOT-363 •
- Case Material: Molded Plastic. UL Flammability • Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C .
- Terminals: Solderable per MIL-STD-202, Method 208 .
- Lead Free Plating (Matte Tin Finish annealed over • Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.006 grams (approximate)



| SOT-363 | | | | | | | | | |
|---------|----------------------|--------------|--|--|--|--|--|--|--|
| Dim | Min | Max | | | | | | | |
| Α | 0.10 | 0.30 | | | | | | | |
| В | 1.15 | 1.35 | | | | | | | |
| С | 2.00 2.20 | | | | | | | | |
| D | 0.65 N | 0.65 Nominal | | | | | | | |
| F | 0.30 | 0.40 | | | | | | | |
| н | 1.80 | 2.20 | | | | | | | |
| J | | 0.10 | | | | | | | |
| к | 0.90 1.00 | | | | | | | | |
| L | 0.25 | 0.40 | | | | | | | |
| М | 0.10 | 0.25 | | | | | | | |
| α | 0° | 8° | | | | | | | |
| All Dir | All Dimensions in mm | | | | | | | | |

Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|-----------------------------------------|-----------------------------------|-------------|------|
| Collector-Base Voltage | V _{CBO} | 60 | V |
| Collector-Emitter Voltage | V _{CEO} | 40 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current - Continuous | lc | 200 | mA |
| Power Dissipation (Note 1) | P _d | 200 | mW |
| Thermal Resistance, Junction to Ambient | R _{0JA} | 625 | °C/W |
| Operating and Storage Temperature Range | T _i , T _{STG} | -55 to +150 | °C |

1. Device mounted on FR-4 PCB; pad layout as shown on Diodes Inc. suggested pad layout documents APO2001, Notes: which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

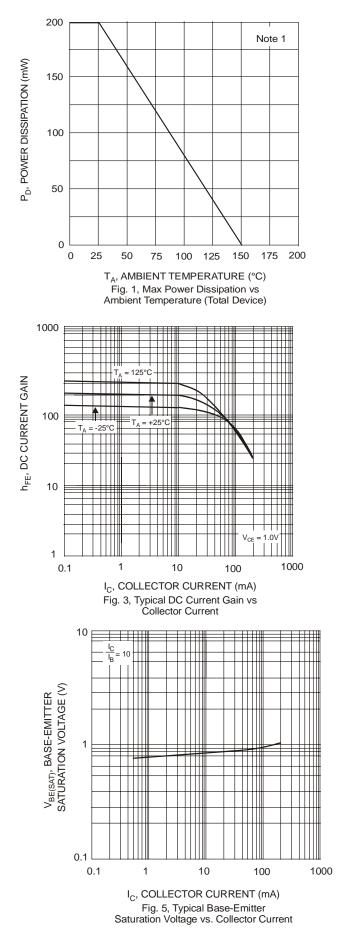
2. No purposefully added lead.

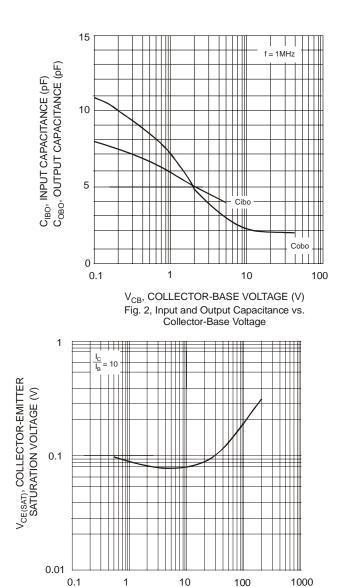


| Electrical Characteristics @T _A = 25°C unless otherwise specified | | | | | | | | | |
|------------------------------------------------------------------------------|----------------------|-----------------------------|--------------|--------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|--|
| Characteristic | Symbol | Min | Max | Unit | Test Condition | | | | |
| OFF CHARACTERISTICS (Note 3) | | | · | | • | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | 60 | _ | V | $I_{\rm C} = 10 \mu A, I_{\rm E} = 0$ | | | | |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | 40 | _ | V | $I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$ | | | | |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | 5.0 | _ | V | $I_{E} = 10 \mu A, I_{C} = 0$ | | | | |
| Collector Cutoff Current | I _{CEX} | _ | 50 | nA | $V_{CE} = 30V, V_{EB(OFF)} = 3.0V$ | | | | |
| Base Cutoff Current | I _{BL} | _ | 50 | nA | $V_{CE} = 30V, V_{EB(OFF)} = 3.0V$ | | | | |
| ON CHARACTERISTICS (Note 3) | | | • | | - | | | | |
| DC Current Gain | h _{FE} | 40 70 100 60 30 | 300 | _ | $ \begin{array}{ll} I_{C} = & 100 \mu A, \ V_{CE} = & 1.0 V \\ I_{C} = & 1.0 m A, \ V_{CE} = & 1.0 V \\ I_{C} = & 10 m A, \ V_{CE} = & 1.0 V \\ I_{C} = & 50 m A, \ V_{CE} = & 1.0 V \\ I_{C} = & 100 m A, \ V_{CE} = & 1.0 V \\ \end{array} $ | | | | |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | | 0.20 0.30 | V | $\begin{split} I_{C} &= 10 \text{mA}, \ I_{B} = 1.0 \text{mA} \\ I_{C} &= 50 \text{mA}, \ I_{B} = 5.0 \text{mA} \end{split}$ | | | | |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | 0.65 | 0.85 0.95 | V | $\begin{split} I_{C} &= 10 mA, \ I_{B} = 1.0 mA \\ I_{C} &= 50 mA, \ I_{B} = 5.0 mA \end{split}$ | | | | |
| SMALL SIGNAL CHARACTERISTICS | | | | | | | | | |
| Output Capacitance | C _{obo} | _ | 4.0 | pF | $V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$ | | | | |
| nput Capacitance | C _{ibo} | _ | 8.0 | pF | $V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$ | | | | |
| nput Impedance | h _{ie} | 1.0 | 10 | kΩ | | | | | |
| /oltage Feedback Ratio | h _{re} | 0.5 | 8.0 | x 10 ⁻⁴ | $V_{CE} = 10V, I_{C} = 1.0mA,$ | | | | |
| Small Signal Current Gain | h _{fe} | 100 | 400 | _ | f = 1.0kHz | | | | |
| Output Admittance | h _{oe} | 1.0 | 40 | μS | | | | | |
| Current Gain-Bandwidth Product | f⊤ | 300 | _ | MHz | $V_{CE} = 20V, I_C = 10mA,$ f = 100MHz | | | | |
| Noise Figure | NF | | 5.0 | dB | $V_{CE} = 5.0V, I_C = 100\mu A, R_S = 1.0k\Omega, f = 1.0kHz$ | | | | |
| SWITCHING CHARACTERISTICS | · · · · · | | | | | | | | |
| Delay Time | t _d | — | 35 | ns | $V_{CC} = 3.0V, I_{C} = 10mA,$ | | | | |
| Rise Time | t _r | _ | 35 | ns | $V_{BE(off)} = -0.5V, I_{B1} = 1.0mA$ | | | | |
| Storage Time | t _s | _ | 200 | ns | $V_{CC} = 3.0V, I_C = 10mA,$ | | | | |
| Fall Time | t _f | _ | 50 | ns | $I_{B1} = I_{B2} = 1.0 \text{mA}$ | | | | |

Notes: 3. Short duration pulse test used to minimize self-heating.







I_C, COLLECTOR CURRENT (mA) Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current



Ordering Information (Note 4)

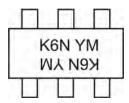
| Device | Packaging | Shipping | | | |
|--------------|-----------|------------------|--|--|--|
| MMDT3904-7-F | SOT-363 | 3000/Tape & Reel | | | |

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

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Marking Information



K6N = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Data Code Key

Code

| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | J | к | L | М | Ν | Р | R | S | Т | U | V | W | Х | Y | Z |
| | | | | | | | | ÷ | | | | ÷ | | | |
| Month | Jan | Feb | o I | Mar | Apr | Мау | Ju | n | Jul | Aug | Sep | Oc | t M | lov | Dec |

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